

FORM PTO-1449			Atty. Docket No. XA-9693A	Appln. No. 10/701,497
<u>LIST OF DOCUMENTS CITED BY APPLICANT</u>			Applicant Yoshitaka SASAGO et al.	
			Filing Date HEREWITH 11-06-03	Group 2822

## U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
JM	AA	5,095,344	03/10/92	Harari (corrs. to JP 2694618)	357	23.5	
JM	AB	5,739,569	4/98	Chen	257	322	
JM	AC	5,773,863	6/98	Burr et al.	257	316	
JM	AD	6,492,690	12/02	Ueno et al.	257	316	
JM	AE	4,561,004	12/85	Kuo et al.	257	319	
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JM	AH	5,640,032	6/97	Tomioka	257	316	
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## FOREIGN PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
AJ		2694618	09/12/97	Japan			No
AK		9-321157	12/12/97	Japan			Abstract
AL							
AM							
AN							
AO							

## OTHER (including author, title, date, pertinent pages, etc.)

AP	"Ohyo Butsuri" (or APPLIED PHYSICS), The Japan Society of Applied Physics, Vol. 65, No. 11, November 10, 1996, pp. 1114-1124
AQ	K. Naruko et al., "A New Flash-Erase EEPROM Cell with a Sidewall Select-Gate on its Source Side", IEDM, 1989, pp. 603-606.
AR	

Examiner	Date Considered
T. M. Thomas	12-01-05
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.	